NSN 5961-00-444-6633 Transistor - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5961-00-444-6633
Inclosure Material:
Metal
Overall Length:
Between 0.240 inches and 0.260 inches
Terminal Length:
0.500 inches
Overall Diameter:
Between 0.335 inches and 0.370 inches
Internal Configuration:
Junction contact
Joint Electronic Device Engineering Council/jedec/case Outline Designation:
To-5
Electrode Internally-electrically Connected To Case:
Collector
Mounting Method:
Terminal
Terminal Circle Diameter:
0.200 inches
Features Provided:
Hermetically sealed case
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
60.0 collector to base voltage/static/emitter open and 60.0 collector to emitter voltage/static/base open and 7.0 emitter to base voltage,
static, collector open
Current Rating Per Characteristic:
1.00 amperes source cutoff current
Power Rating Per Characteristic:
6.0 watts small-signal input power, common-collector absolute
Transfer Ratio:
30.0 static forward current transfer ratio, common-emitter and 150.0 static forward current transfer ratio, common-emitter
Maximum Operating Tempurature Per Measurement Point:
200.0 degrees celsius junction
Special Features:
Junction pattern arrangement: pnp
Test Data Document:
13499-352-0695 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc
excludes any specification, standard or other document that may be referenced in a basic governing drawing)
Terminal Type And Quantity:
3 uninsulated wire lead
Shelf Life:
N/a

Unit Of Measure:

NSN 5961-00-444-6633

Transistor - Page 2 of 2



Demilitarization:

No

Fiig:

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